

isc Silicon NPN Darlington Power Transistor

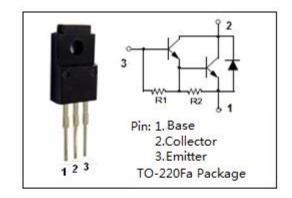
BDT61BF

DESCRIPTION

- · High DC Current Gain
- · Low Saturation Voltage
- Complement to Type BDT60BF
- Minimum Lot-to-Lot variations for robust device performance and reliable operation

APPLICATIONS

 Designed for use as complementary AF push-pull output stage applications

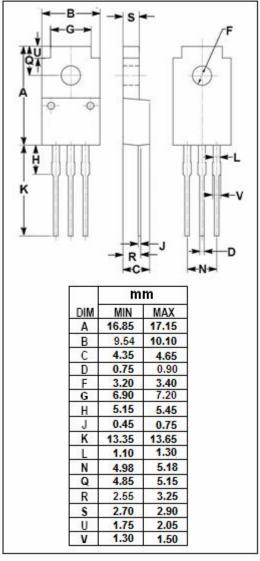


ABSOLUTE MAXIMUM RATINGS(Ta=25℃)

ABOOLOTE MAXIMOM (ATMOO(1a-20 C)								
SYMBOL	PARAMETER	VALUE	UNIT					
V _{CBO}	Collector-Base Voltage	100	V					
V _{CEO}	Collector-Emitter Voltage	100	V					
V _{EBO}	Emitter-Base Voltage	5	V					
Ic	Collector Current-Continuous	4	А					
I _{CP}	Collector Current-Peak	6	Α					
I _B	Base Current-Continuous	0.1	Α					
Pc	Collector Power Dissipation @ T _a =25°C	17	w					
	Collector Power Dissipation @ T _C =25°C	25						
TJ	Junction Temperature 150		$^{\circ}$					
T _{stg}	Storage Temperature Range	-65~150	$^{\circ}$					

THERMAL CHARACTERISTICS

SYMBOL	PARAMETER	MAX	UNIT
R _{th j-c}	Thermal Resistance, Junction to Case	5	°C/W
R _{th j-a}	Thermal Resistance, Junction to Ambient	7.35	°C/W





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ELECTRICAL CHARACTERISTICS

T_c=25℃ unless otherwise specified

SYMBOL	PARAMETER	CONDITIONS	MIN	TYP.	MAX	UNIT
V _{CEO(SUS)}	Collector-Emitter Breakdown Voltage	I _C = 30mA; I _B = 0	100			V
V _{CE(sat)}	Collector-Emitter Saturation Voltage	I _C = 1.5A; I _B = 6mA			2.5	V
V _{BE(on)}	Base-Emitter On Voltage	Ic= 4A; Vc= 3V			2.5	V
І _{сво}	Collector Cutoff Current	V _{CB} = 30V; I _E = 0			0.2	- mA
		V _{CB} = 50V; I _E = 0; T _C = 150°C			1.0	
I _{CEO}	Collector Cutoff Current	V _{CE} = 50V; I _B = 0			0.2	mA
I _{EBO}	Emitter Cutoff Current	V _{EB} = 5V; I _C = 0			5	mA
h _{FE-1}	DC Current Gain	I _C = 0.5A ; V _{CE} = 3V		2000		
h _{FE-2}	DC Current Gain	I _C = 1.5A ; V _{CE} = 3V	750			
h _{FE-3}	DC Current Gain	I _C = 4A ; V _{CE} = 3V		1000		

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